## NSN 5961-00-256-3396

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View Online at https://aerobasegroup.com/nsn/5961-00-256-3396 **Inclosure Material:** Glass and plastic **Overall Length:** 0.500 inches **Terminal Length:** 0.900 inches **Overall Height:** 0.200 inches **Overall Width:** 0.450 inches **Function For Which Designed:** Switching **Component Name And Quantity:** 4 semiconductor device diode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 75.0 working peak reverse voltage all semiconductor device diode **Current Rating Per Characteristic:** 115.00 milliamperes source cutoff current preset all semiconductor device diode and 75.00 milliamperes forward current, average absolute all semiconductor device diode **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Precious Material And Location:** Leads gold **Precious Material:** Gold **Terminal Type And Quantity:** 8 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** 

No

Demilitarization:

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